

STD840DN40

Dual NPN high voltage transistors in a single package

Datasheet — production data

Features

- Low V_{CE(sat)}
- Simplified circuit design
- Reduced component count
- Fast switching speed

Applications

- Compact fluorescent lamp (CFL) 220 V mains
- Electronic ballast for fluorescent lighting

Description

This device is a dual NPN high voltage power transistor manufactured using multi-epitaxial planar technology. It is housed in a dual-island DIP-8 package, with separated terminals for a high degree of mounting flexibility.

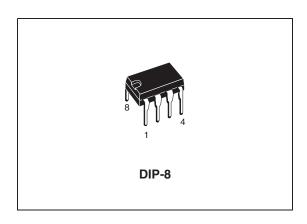


Figure 1. Internal schematic diagram

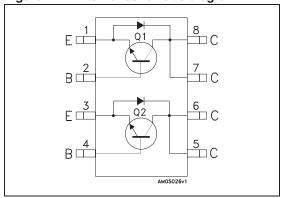


Table 1. Device summary

Order code	Marking	Package	Packaging
STD840DN40	D840DN40	DIP-8	Tube

Electrical ratings STD840DN40

1 Electrical ratings

Table 2. Absolute maximum ratings

Symbol	Parameter	Value	Unit
V _{CBO}	Collector-base voltage (I _E = 0)	700	V
V _{CEO}	Collector-emitter voltage (I _B = 0)	400	V
V _{EBO}	Emitter-base voltage ($I_C = 0$, $I_B = 1.5$ A, $t_p < 10$ ms)	V _{(BR)EBO}	V
I _C	Collector current	4	Α
I _{CM}	Collector peak current (t _P < 5 ms)	8	Α
I _B	Base current	1.5	Α
I _{BM}	Base peak current (t _P < 5 ms)	3	Α
В	Total dissipation at T _{amb} = 25 °C single transistor	3	W
P _{TOT}	Total dissipation at T _{case} = 25 °C single transistor	45	W
T _{STG} Storage temperature		-65 to 150	°C
T _J Max. operating junction temperature		150	°C

Table 3. Thermal data

Symbol	Parameter	Value	Unit
R _{thJA} ⁽¹⁾	Thermal resistance junction-ambient (single transistor)	42	°C/W
R _{thJC}	Thermal resistance junction-case (single transistor)	2.7	°C/W

^{1.} Device mounted on PCB area of 25 mm².

2 Electrical characteristics

 T_{case} = 25 °C unless otherwise specified.

Table 4. Electrical characteristics

Symbol	Parameter	Test conditions	Min.	Тур.	Max.	Unit
I _{CES}	Collector cut-off current (V _{BE} = 0)	V _{CE} = 700 V V _{CE} = 700 V T _c = 125 °	С		100 500	μ Α μ Α
I _{CEO}	Collector cut-off current (I _B = 0)	V _{CE} = 400 V			250	μΑ
V _{(BR)EBO}	Emitter-base breakdown voltage (I _C = 0)	I _E = 10 mA	9		18	V
V _{CEO(sus)} ⁽¹⁾	Collector-emitter sustaining voltage (I _B = 0)	I _C = 10 mA	400			V
V _{CE(sat)} ⁽¹⁾	Collector-emitter saturation voltage	$I_C = 1 A$ $I_B = 0$ $I_C = 2 A$ $I_B = 0$			0.5 1	V V
V _{BE(sat)} ⁽¹⁾	Base-emitter saturation voltage	$I_C = 1 A$ $I_B = 0$ $I_C = 2 A$ $I_B = 0$			1.2 1.3	V V
h _{FE} ⁽¹⁾	DC current gain	$I_C = 10 \text{ mA}$ $V_{CE} = I_C = 2 \text{ A}$ $V_{CE} = I_C = 2 \text{ A}$			24	
V_{F}	Diode forward voltage	I _F = 1 A			2.5	V
t _s	Resistive load Storage time Fall time	$I_C = 1 \text{ A}$ $I_{B1} = -I_{B2} = 0$ $V_{CC} = 125 \text{ V}$ $I_p = 20$		2.5 0.2		μs μs

^{1.} Pulse test: pulse duration \leq 300 µs, duty cycle \leq 2 %.

Electrical characteristics STD840DN40

2.1 Electrical characteristics (curves)

Figure 2. DC current gain $(V_{CE} = 1 V)$

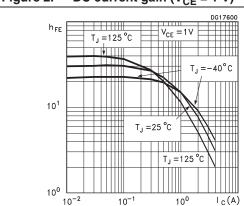


Figure 3. DC current gain $(V_{CE} = 5 V)$

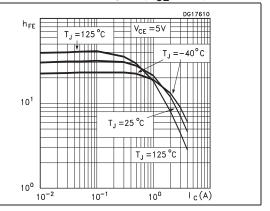
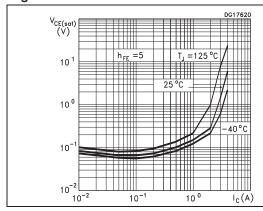


Figure 4. Collector-emitter saturation voltage Figure 5. Base-emitter saturation voltage



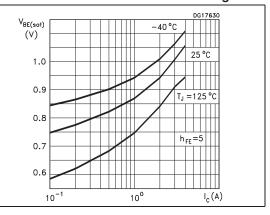


Figure 6. Freewheel diode forward voltage

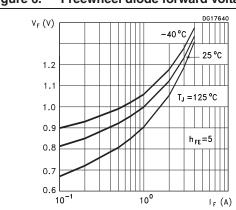
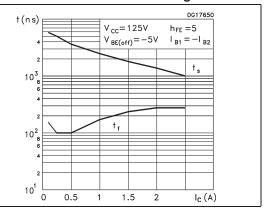


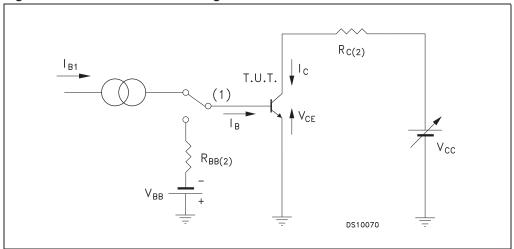
Figure 7. Resistive load switching time



STD840DN40 Test circuit

3 Test circuit

Figure 8. Resistive load switching test circuit



- 1. Fast electronic switch
- 2. Non-inductive resistor

4 Package mechanical data

In order to meet environmental requirements, ST offers these devices in different grades of ECOPACK packages, depending on their level of environmental compliance. ECOPACK specifications, grade definitions and product status are available at: www.st.com. ECOPACK is an ST trademark.

Table 5. DIP-8 mechanical data

Dim		mm.	
Dim.	Min.	Тур.	Max.
А			4.80
A1	0.50		
A2	3.10		3.50
A3	1.40		1.60
b	0.38		0.55
b1	0.38		0.51
b2	1.47		1.57
b3	0.89		1.09
С	0.21		0.35
c1	0.20		0.30
D	9.10		9.30
D1	0.13		
Е	7.62		8.25
E1	6.25		6.45
е		2.54	
eA		7.62	
eB	7.62		10.90
eC	0		1.52
L	2.92		3.81

GC GAUGE PLANE 0.38 eBA3 8145726_A

Figure 9. Drawing dimension DIP-8

Revision history STD840DN40

5 Revision history

Table 6. Document revision history

Date	Revision	Changes
18-Nov-2009	1	Initial release.
16-Apr-2010	2	Inserted P _{TOT} and R _{thJA} values <i>Table 2</i> and <i>Table 3 on page 2</i> .
23-Oct-2012	3	Modified P _{TOT} and R _{thJA} values in <i>Table 2</i> and <i>Table 3 on page 2</i> . Minor text changes.

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